Amplifier Transistors PNP Silicon

COLLECTOR

2
BASE

3
EMITTER

BC327,-16,-25 BC328,-16,-25



MAXIMUM RATINGS

| Rating | Symbol | BC327 | BC328 | Unit |
|---|-----------------------------------|-------------|-------|---------------|
| Collector-Emitter Voltage | VCEO | -45 | -25 | Vdc |
| Collector-Base Voltage | Vсво | -50 | -30 | Vdc |
| Emitter-Base Voltage | VEBO | -5.0 | | Vdc |
| Collector Current — Continuous | IC | -800 | | mAdc |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | PD | 625 5.0 | | mW mW/°C |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | PD | 1.5 12 | | Watt mW/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | | °C |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|------|------|
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 200 | °C/W |
| Thermal Resistance, Junction to Case | R_{θ} JC | 83.3 | °C/W |

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit | | |
|--|----------------|----------|------------|--------|--------------|------|--|
| OFF CHARACTERISTICS | | | | | | | |
| Collector – Emitter Breakdown Voltage (I _C = -10 mA, I _B = 0) | BC327 BC328 | V(BR)CEO | -45 -25 | _ _ | _ _ | Vdc | |
| Collector – Emitter Breakdown Voltage ($I_C = -100 \mu A, I_E = 0$) | BC327 BC328 | V(BR)CES | -50 -30 | _ _ | _ _ | Vdc | |
| Emitter-Base Breakdown Voltage (IE = -10 μ A, IC = 0) | | V(BR)EBO | -5.0 | _ | _ | Vdc | |
| Collector Cutoff Current $(V_{CB} = -30 \text{ V}, I_{E} = 0)$ $(V_{CB} = -20 \text{ V}, I_{E} = 0)$ | BC327 BC328 | ICBO | _ _ | _ _ | -100 -100 | nAdc | |
| Collector Cutoff Current $(V_{CE} = -45 \text{ V}, V_{BE} = 0)$ $(V_{CE} = -25 \text{ V}, V_{BE} = 0)$ | BC327 BC328 | ICES | _ _ | _ _ | -100 -100 | nAdc | |
| Emitter Cutoff Current (V _{EB} = -4.0 V, I _C = 0) | | IEBO | _ | _ | -100 | nAdc | |

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

| Characteristic | | Symbol | Min | Тур | Max | Unit |
|---|---|----------------------|-------------------------|------------------|-------------------|------|
| ON CHARACTERISTICS | | | | | | |
| DC Current Gain $(I_C = -100 \text{ mA}, V_{CE} = -1.0 \text{ V})$ $(I_C = -300 \text{ mA}, V_{CE} = -1.0 \text{ V})$ | BC327/BC328 BC327–16/BC328–16 BC327–25/BC328–25 | hFE | 100 100 160 40 | _ _ _ _ | 630 250 400 | _ |
| Base–Emitter On Voltage (I _C = -300 mA, V _{CE} = -1.0 V) | | V _{BE(on)} | _ | _ | -1.2 | Vdc |
| Collector-Emitter Saturation Voltage (I _C = -500 mA, I _B = -50 mA) | | V _{CE(sat)} | _ | _ | -0.7 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | • | | | | |
| Output Capacitance (V _{CB} = -10 V, I _E = 0, f = 1.0 MHz) | | C _{ob} | _ | 11 | _ | pF |
| Current – Gain — Bandwidth Product (I _C = -10 mA, V _{CE} = -5.0 V, f = 100 MHz) | | fŢ | _ | 260 | _ | MHz |

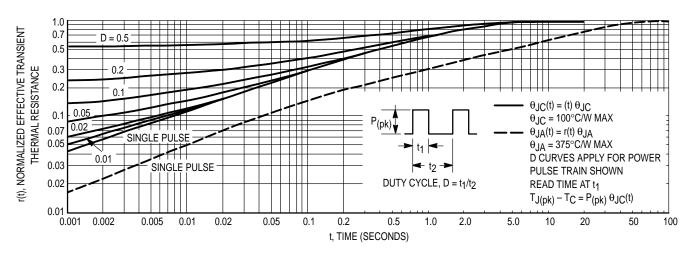


Figure 1. Thermal Response

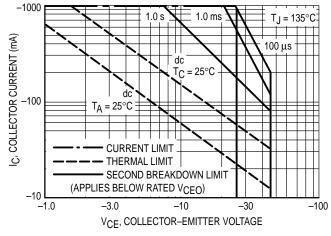


Figure 2. Active Region — Safe Operating Area

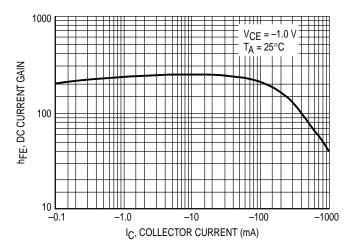


Figure 3. DC Current Gain

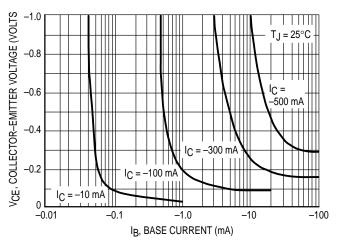


Figure 4. Saturation Region

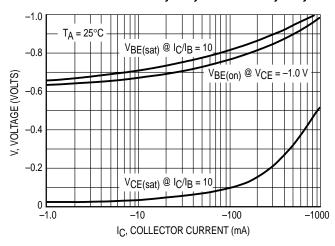


Figure 5. "On" Voltages

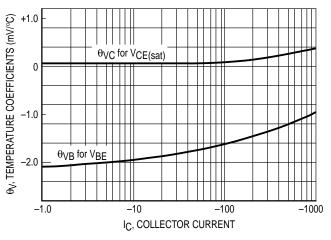


Figure 6. Temperature Coefficients

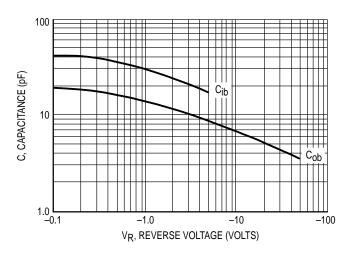
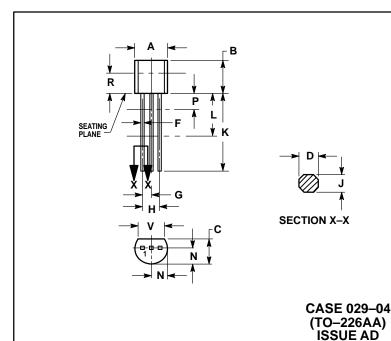


Figure 7. Capacitances

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K
 MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | INC | HES | MILLIM | IETERS |
|-----|-------|-------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.175 | 0.205 | 4.45 | 5.20 |
| В | 0.170 | 0.210 | 4.32 | 5.33 |
| С | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.022 | 0.41 | 0.55 |
| F | 0.016 | 0.019 | 0.41 | 0.48 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| Н | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | | 12.70 | |
| L | 0.250 | | 6.35 | |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| Р | | 0.100 | _ | 2.54 |
| R | 0.115 | | 2.93 | |
| ٧ | 0.135 | | 3.43 | |

STYLE 17: PIN 1. COLLECTOR 2. 3. BASE EMITTER

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